

### **DESCRIPTION**

The SPN340T06 is the N-Channel enhancement mode power field effect transistor which is produced using super high cell density DMOS trench technology. This high density process is especially tailored to minimize on-state resistance. These devices are particularly suitable for synchronous rectifier application, Motor control power management and other Power Tool circuits. It has been optimized for low gate charge, low RDS(ON) and fast switching speed..

### **FEATURES**

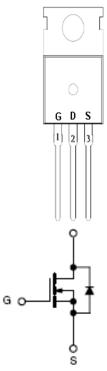
- 60V/340A, RDS(ON)=1.9m $\Omega$ @VGS=10V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ Enhanced Avalanche Ruggedness
- ◆ TO-220-3L package design

### **APPLICATIONS**

- DC/DC Converter
- Hard Switching and High Speed Circuit
- Synchronous Buck Converter
- Power Tools
- UPS
- Motor Control

### PIN CONFIGURATION

TO-220-3L



#### **PART MARKING**



PIN DESCRIPTION				
Pin	Symbol	Description		
1	G	Gate		
2	D	Drain		
3	S	Source		

### **ORDERING INFORMATION**

Part Number	Package	Part Marking
SPN340T06T220TGB	TO-220-3L	SPN340T06

<sup>※</sup> SPN340T060T220TGB: Tube; Pb − Free; Halogen − Free

### ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter	Symbol	Typical	Unit	
Drain-Source Voltage		VDSS	60	V
Gate –Source Voltage		VGSS	±20	V
Continue Dair Consul(Cilian Linital)	Tc=25°C		340	
Continuous Drain Current(Silicon Limited)	Tc=70°C	ID	240	A
Continuous Drain Current(Package Limited)	Tc=25°C		120	
Pulsed Drain Current		Ідм	900	A
Power Dissipation Ta=25°C		PD	104	W
Avalanche Energy with Single Pulse (Tc=25°C, L=1mH)		EAS	702	mJ
Operating Junction Temperature		TJ	-55/150	°C
Storage Temperature Range		Tstg	-55/150	°C
Thermal Resistance-Junction to Case		RөJC	1.2	°C/W

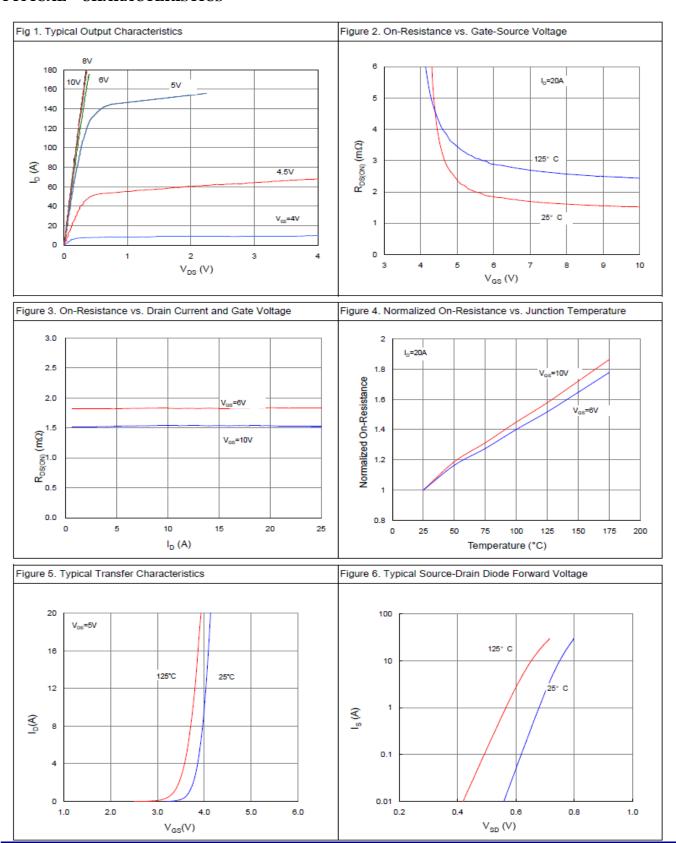


## **ELECTRICAL CHARACTERISTICS**

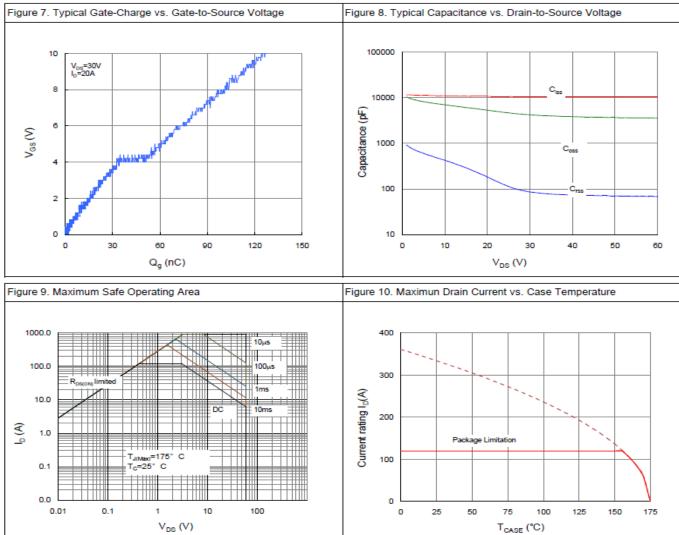
(TA=25°C Unless otherwise noted)

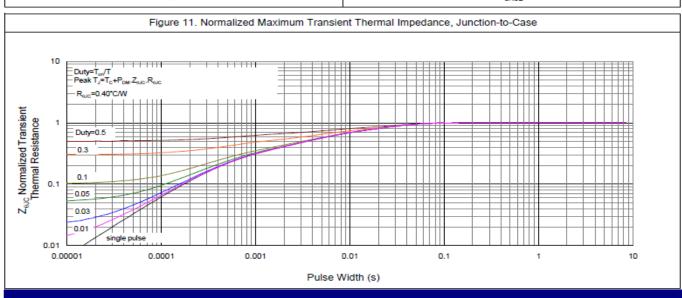
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static	I		II.	ı			
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	60			V	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	2	3	4	]	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V T <sub>J</sub> = 25 °C			1	uA	
	IDSS	V <sub>DS</sub> =60,V <sub>GS</sub> =0V T <sub>J</sub> =100 °C			100		
On-State Drain Current	ID(on)	Vds≥5V,Vgs =10V	60			A	
Drain-Source On-Resistance	RDS(on)	Vgs=10V,Id=20A		1.67	1.9	mΩ	
Forward Transconductance	gfs	Vds=5V,Id=20A		92		S	
Gate Resistance	RG	VGS=0V,VDS=Open, f=1MHz		0.7		Ω	
Diode Forward Voltage	Vsd	I <sub>F</sub> =20A,V <sub>GS</sub> =0V		0.9	1.2	V	
Dynamic							
Total Gate Charge	Qg			124		nC	
Gate-Source Charge	Qgs	VDS=30V,VGS=10V ID=20A		30			
Gate-Drain Charge	Qgd	-ID-20A		20			
Input Capacitance	Ciss			10570		pF	
Output Capacitance	Coss	VDS=30V,VGS=0V f=1MHz		4050			
Reverse Transfer Capacitance	Crss			84		1	
Turn-On Time	td(on)			35		nS	
	tr	VDD=30V, ID=20A,		27			
T Off T'	td(off)	$V_{GS}=10V, R_{G}=3\Omega$		70			
Turn-Off Time	tf			15			

### TYPICAL CHARACTERISTICS

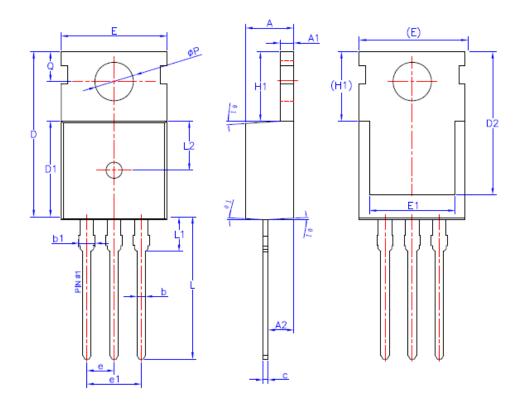


### TYPICAL CHARACTERISTICS





# **TO-220-3L PACKAGE OUTLINE**



SYMBOL	MIN	NOM	MAX
A	4.40	4.50	4.60
A1	1.27	1.30	1.33
A2	2.30	2.40	2.50
b	0.70	0.60	0.90
b1	-	-	1.40
С	0.45	0.50	0.60
D	15.30	15.70	16.10
D1	9.10	9.20	9.30
D2	13.10	-	13.70
Е	9.70	9.90	10.20
E1	7.80	8.00	8.20
е	2.54BSC		
e1	5.08BSC		
H1	6.30	6.50	6.70
L	12.78	13.08	13.38
L1	-	-	3.50
L2	4.6REF		
φP	3.55	3.60	3.65
Q	2.73	-	2.87
<b>0</b> 1	1°	3°	5°

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